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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	180MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I²C, IrDA, LINbus, SAI, SDIO, SPI, UART/USART, USB, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, I²S, LCD, POR, PWM, WDT
Number of I/O	114
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	384K x 8
Voltage - Supply (Vcc/Vdd)	1.7V ~ 3.6V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	169-UFBGA
Supplier Device Package	169-UFBGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f479aih6

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2.19 Power supply supervisor

2.19.1 Internal reset ON

On packages embedding the PDR_ON pin, the power supply supervisor is enabled by holding PDR_ON high. On the other package, the power supply supervisor is always enabled.

The device has an integrated power-on reset (POR)/ power-down reset (PDR) circuitry coupled with a Brownout reset (BOR) circuitry. At power-on, POR/PDR is always active and ensures proper operation starting from 1.8 V. After the 1.8 V POR threshold level is reached, the option byte loading process starts, either to confirm or modify default BOR thresholds, or to disable BOR permanently. Three BOR thresholds are available through option bytes. The device remains in reset mode when V_{DD} is below a specified threshold, $V_{POR/PDR}$ or V_{BOR} , without the need for an external reset circuit.

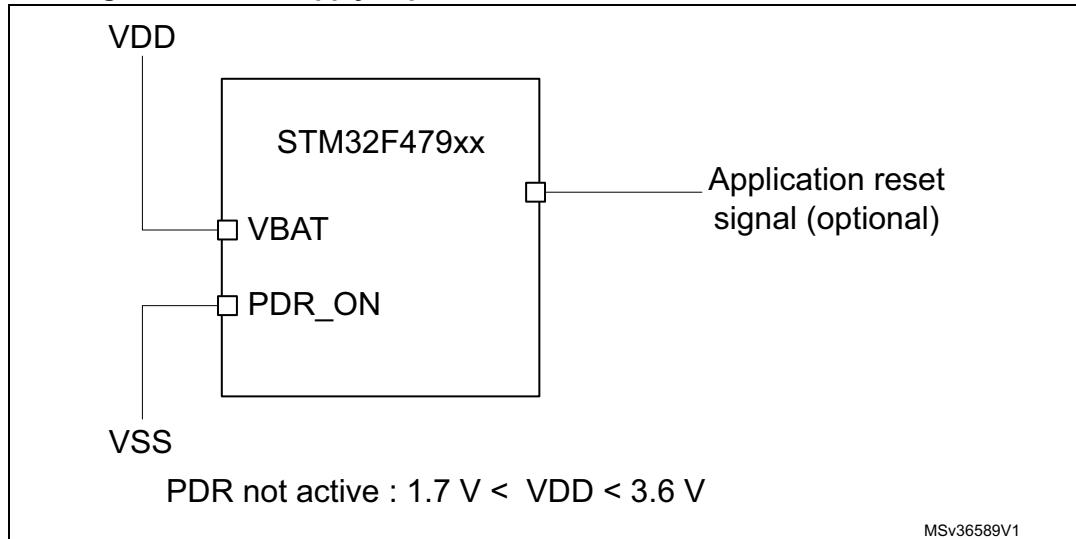
The device also features an embedded programmable voltage detector (PWD) that monitors the V_{DD}/V_{DDA} power supply and compares it to the V_{PWD} threshold. An interrupt can be generated when V_{DD}/V_{DDA} drops below the V_{PWD} threshold and/or when V_{DD}/V_{DDA} is higher than the V_{PWD} threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PWD is enabled by software.

2.19.2 Internal reset OFF

This feature is available only on packages featuring the PDR_ON pin. The internal power-on reset (POR) / power-down reset (PDR) circuitry is disabled through the PDR_ON pin.

An external power supply supervisor should monitor V_{DD} and NRST and should maintain the device in reset mode as long as V_{DD} is below a specified threshold. PDR_ON must be connected to VSS, as shown in [Figure 8](#).

Figure 8. Power supply supervisor interconnection with internal reset OFF



The V_{DD} specified threshold, below which the device must be maintained under reset, is 1.7 V (see [Figure 9](#)).

A comprehensive set of power-saving mode allows to design low-power applications.

Table 10. STM32F479xx pin and ball definitions (continued)

Pin number										Pin name (function after reset) ⁽¹⁾	Pin types	I/O structures	Notes	Alternate functions	Additional functions
LQFP100	LQFP144	UFBGA169	WL CSP168	UFBGA176	LQFP176	LQFP208	TFBGA216								
-	96	D13	G6	H14	116	135	H14	PG8	I/O	FT	-	SPI6_NSS, USART6_RTS, ETH_PPS_OUT, FMC_SDCLK, LCD_G7, EVENTOUT	-	-	
-	-	G9	F2	G12	117	136	G10	VSS	S	-	-	-	-	-	-
65	97	G11	F1	H13	118	137	G11	VDDUSB	S	-	-	-	-	-	-
66	98	F9	F3	H15	119	138	H15	PC6	I/O	FT	-	TIM3_CH1, TIM8_CH1, I2S2_MCK, USART6_TX, SDIO_D6, DCMI_D0, LCD_HSYNC, EVENTOUT	-	-	
67	99	F10	G7	G15	120	139	G15	PC7	I/O	FT	-	TIM3_CH2, TIM8_CH2, I2S3_MCK, USART6_RX, SDIO_D7, DCMI_D1, LCD_G6, EVENTOUT	-	-	
68	100	E10	F4	G14	121	140	G14	PC8	I/O	FT	-	TRACED1, TIM3_CH3, TIM8_CH3, USART6_CK, SDIO_D0, DCMI_D2, EVENTOUT	-	-	
69	101	G10	F5	F14	122	141	F14	PC9	I/O	FT	-	MCO2, TIM3_CH4, TIM8_CH4, I2C3_SDA, I2S_CKIN, QUADSPI_BK1_IO0, SDIO_D1, DCMI_D3, EVENTOUT	-	-	
70	102	D8	E1	F15	123	142	F15	PA8	I/O	FT	-	MCO1, TIM1_CH1, I2C3_SCL, USART1_CK, OTG_FS_SOF, LCD_R6, EVENTOUT	-	-	
71	103	E8	E2	E15	124	143	E15	PA9	I/O	FT	-	TIM1_CH2, I2C3_SMBA, SPI2_SCK/I2S2_CK, USART1_TX, DCMI_D0, EVENTOUT	OTG_FS_VBUS	-	
72	104	E9	E3	D15	125	144	D15	PA10	I/O	FT	-	TIM1_CH3, USART1_RX, OTG_FS_ID, DCMI_D1, EVENTOUT	-	-	
73	105	A13	F7	C15	126	145	C15	PA11	I/O	FT	-	TIM1_CH4, USART1_CTS, CAN1_RX, OTG_FS_DM, LCD_R4, EVENTOUT	-	-	
74	106	A12	F6	B15	127	146	B15	PA12	I/O	FT	-	TIM1_ETR, USART1_RTS, CAN1_TX, OTG_FS_DP, LCD_R5, EVENTOUT	-	-	
75	107	A11	D1	A15	128	147	A15	PA13(JTMS-SWDIO)	I/O	FT	-	JTMS-SWDIO, EVENTOUT	-	-	
76	108	D12	D2	F13	129	148	E11	VCAP2	S	-	-	-	-	-	
-	109	D11	C1	F12	130	149	F10	VSS	S	-	-	-	-	-	

6. If the device is delivered in an WLCSP168, UFBGA169, UFBGA176, LQFP176 or TFBGA216 package, and the BYPASS_REG pin is set to VDD (Regulator OFF/internal reset ON mode), then PA0 is used as an internal Reset (active low).
7. PI0 and PI1 cannot be used for I2S2 full-duplex mode.

Table 12. Alternate function (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS	TIM1/2	TIM3/4/ 5	TIM8/9/ 10/11	I2C1/2/3	SPI1/2/3 /4/5/6	SPI2/3/ SAI1	SPI2/3/ USART 1/2/3	USAR T6/ UART 4/5/7/ 8	CAN1/2/ TIM12/ 13/14/ QUAD SPI/LCD	QUAD SPI/OT G2_HS /OTG1 _FS	ETH	FMC/ SDIO/ OTG2_ FS	DCMI/ DSI HOST	LCD	SYS
Port B	PB0	-	TIM1_CH2N	TIM3_CH3	TIM8_CH2_N	-	-	-	-	-	LCD_R3	OTG_HS_UPLP1_D1	ETH_MII_RXD2	-	-	LCD_G1	EVENT OUT
	PB1	-	TIM1_CH3N	TIM3_CH4	TIM8_CH3_N	-	-	-	-	-	LCD_R6	OTG_HS_UPLP1_D2	ETH_MII_RXD3	-	-	LCD_G0	EVENT OUT
	PB2	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	EVENT OUT
	PB3	JTDO / TRACES WO	TIM2_CH2		-	-	SPI1_SCK	SPI3_SCK/ I2S3_CK	-	-	-	-	-	-	-	-	EVENT OUT
	PB4	NJTRST	-	TIM3_CH1	-	-	SPI1_MISO	SPI3_MIS_O	I2S3ext_SD	-	-	-	-	-	-	-	EVENT OUT
	PB5	-	-	TIM3_CH2	-	I2C1_SMBA	SPI1_MOSI	SPI3_MOS_I/I2S3_SD		-	CAN2_RX	OTG_HS_UPLP1_D7	ETH_PPS_OUT	FMC_SDCKE1	DCMI_D10	LCD_G7	EVENT OUT
	PB6	-	-	TIM4_CH1	-	I2C1_SCL	-	-	USART1_TX	-	CAN2_TX	QUADSPI_BK1_NCS	-	FMC_SDNE1	DCMI_D5		EVENT OUT
	PB7	-	-	TIM4_CH2	-	I2C1_SDA	-	-	USART1_RX	-	-	-	-	FMC_NL	DCMI_VSYNC		EVENT OUT
	PB8	-	-	TIM4_CH3	TIM10_CH1	I2C1_SCL	-	-	-	-	CAN1_RX	-	ETH_MII_RXD3	SDIO_D4	DCMI_D6	LCD_B6	EVENT OUT
	PB9	-	-	TIM4_CH4	TIM11_CH1	I2C1_SDA	SPI2_NSS/I I2S2_WS	-	-	-	CAN1_TX	-	-	SDIO_D5	DCMI_D7	LCD_B7	EVENT OUT
	PB10	-	TIM2_CH3	-	-	I2C2_SCL	SPI2_SCK/I I2S2_CK	-	USART3_TX	-	QUADSPI_BK1_NCS	OTG_HS_UPLP1_D3	ETH_MII_RX_ER	-	-	LCD_G4	EVENT OUT
	PB11	-	TIM2_CH4	-	-	I2C2_SDA		-	USART3_RX	-		OTG_HS_UPLP1_D4	ETH_MII_TX_EN/ETH_RMII_TX_EN	-	DSIHOST_TE	LCD_G5	EVENT OUT
	PB12	-	TIM1_BKIN	-	-	I2C2_SMBA	SPI2_NSS/I I2S2_WS	-	USART3_CK	-	CAN2_RX	OTG_HS_UPLP1_D5	ETH_MII_RXD0/ETH_RMII_TXD0	OTG_HS_ID	-	-	EVENT OUT
	PB13	-	TIM1_CH1N	-	-	-	SPI2_SCK/I I2S2_CK	-	USART3_CTS	-	CAN2_TX	OTG_HS_UPLP1_D6	ETH_MII_RXD1/ETH_RMII_TXD1	-	-	-	EVENT OUT
	PB14	-	TIM1_CH2N	-	TIM8_CH2_N	-	SPI2_MISO	I2S2ext_SD	USART3_RTS	-	TIM12_CH1	-	-	OTG_HS_DM	-	-	EVENT OUT
	PB15	RTC_REFIN	TIM1_CH3N	-	TIM8_CH3_N	-	SPI2_MOSI I2S2_SD	-	-	-	TIM12_CH2	-	-	OTG_HS_DP	-	-	EVENT OUT

Table 12. Alternate function (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS	TIM1/2	TIM3/4/ 5	TIM8/9/ 10/11	I2C1/2/3	SPI1/2/3 /4/5/6	SPI2/3/ SAI1	SPI2/3/ USART 1/2/3	USAR T6/ UART 4/5/7/ 8	CAN1/2/ TIM12/ 13/14/ QUAD SPI/LCD	QUAD SPI/OT G2_HS /OTG1 _FS	ETH	FMC/ SDIO/ OTG2_ FS	DCMI/ DSI HOST	LCD	SYS
Port H	PH0	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	EVENT OUT
	PH1	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	EVENT OUT
	PH2	-	-	-	-	-	-	-	-	-	QUADSPI_BK2_IO0	-	ETH_MII_CRS	FMC_SDC_KE0	-	LCD_R0	EVENT OUT
	PH3	-	-	-	-	-	-	-	-	-	QUADSPI_BK2_IO1	-	ETH_MII_COL	FMC_SDN_E0	-	LCD_R1	EVENT OUT
	PH4	-	-	-	-	I2C2_SCL	-	-	-	-	LCD_G5	OTG_HS_ULPI_N_XT	-	-	-	LCD_G4	EVENT OUT
	PH5	-	-	-	-	I2C2_SDA	SPI5_NSS	-	-	-	-	-	-	FMC_SDN_WE	-	-	EVENT OUT
	PH6	-	-	-	-	I2C2_SMBA	SPI5_SCK	-	-	-	TIM12_CH1	-	ETH_MII_RXD_2	FMC_SDN_E1	-	-	EVENT OUT
	PH7	-	-	-	-	I2C3_SCL	SPI5_MISO	-	-	-	-	-	ETH_MII_RXD_3	FMC_SDC_KE1	DCMI_D9	-	EVENT OUT
	PH8	-	-	-	-	I2C3_SDA	-	-	-	-	-	-	-	FMC_D16	DCMI_HS_YNC	LCD_R2	EVENT OUT
	PH9	-	-	-	-	I2C3_SMBA	-	-	-	-	TIM12_CH2	-	-	FMC_D17	DCMI_D0	LCD_R3	EVENT OUT
	PH10	-	-	TIM5_CH1	-	-	-	-	-	-	-	-	-	FMC_D18	DCMI_D1	LCD_R4	EVENT OUT
	PH11	-	-	TIM5_CH2	-	-	-	-	-	-	-	-	-	FMC_D19	DCMI_D2	LCD_R5	EVENT OUT
	PH12	-	-	TIM5_CH3	-	-	-	-	-	-	-	-	-	FMC_D20	DCMI_D3	LCD_R6	EVENT OUT
	PH13	-	-	-	TIM8_CH1_N	-	-	-	-	-	CAN1_TX	-	-	FMC_D21	-	LCD_G2	EVENT OUT
	PH14	-	-	-	TIM8_CH2_N	-	-	-	-	-	-	-	-	FMC_D22	DCMI_D4	LCD_G3	EVENT OUT
	PH15	-	-	-	TIM8_CH3_N	-	-	-	-	-	-	-	-	FMC_D23	DCMI_D11	LCD_G4	EVENT 'OUT

Table 15. Current characteristics

Symbol	Ratings	Max.	Unit
ΣI_{VDD}	Total current into sum of all V_{DD_x} power lines (source) ⁽¹⁾	290	mA
ΣI_{VSS}	Total current out of sum of all V_{SS_x} ground lines (sink) ⁽¹⁾	- 290	
ΣI_{VDDUSB}	Total current into V_{DDUSB} power line (source)	25	
I_{VDD}	Maximum current into each V_{DD_x} power line (source) ⁽¹⁾	100	
I_{VSS}	Maximum current out of each V_{SS_x} ground line (sink) ⁽¹⁾	- 100	
I_{IO}	Output current sunk by any I/O and control pin	25	
	Output current sourced by any I/Os and control pin	- 25	
ΣI_{IO}	Total output current sunk by sum of all I/O and control pins ⁽²⁾	120	
	Total output current sunk by sum of all USB I/Os	25	
	Total output current sourced by sum of all I/Os and control pins ⁽²⁾	- 120	
$I_{INJ(PIN)}$ ⁽³⁾	Injected current on FT pins ⁽⁴⁾	- 5/+0	
	Injected current on NRST and BOOT0 pins ⁽⁴⁾		
	Injected current on TTa pins ⁽⁵⁾	±5	
$\Sigma I_{INJ(PIN)}$ ⁽⁵⁾	Total injected current (sum of all I/O and control pins) ⁽⁶⁾	±25	

1. All main power (V_{DD} , V_{DDA}) and ground (V_{SS} , V_{SSA}) pins must always be connected to the external power supply, in the permitted range.
2. This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins referring to high pin count LQFP packages.
3. Negative injection disturbs the analog performance of the device. See note in [Section 5.3.24](#).
4. Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.
5. A positive injection is induced by $V_{IN} > V_{DDA}$ while a negative injection is induced by $V_{IN} < V_{SS}$. $I_{INJ(PIN)}$ must never be exceeded. Refer to [Table 14](#) for the values of the maximum allowed input voltage.
6. When several inputs are submitted to a current injection, the maximum $\Sigma I_{INJ(PIN)}$ is the absolute sum of the positive and negative injected currents (instantaneous values).

Table 16. Thermal characteristics

Symbol	Ratings	Value	Unit
T_{STG}	Storage temperature range	- 65 to +150	°C
T_J	Maximum junction temperature	125	°C

Table 17. General operating conditions (continued)

Symbol	Parameter	Conditions ⁽¹⁾	Min	Typ	Max	Unit
V_{12}	Regulator ON: 1.2 V internal voltage on V_{CAP_1}/V_{CAP_2} pins	Power Scale 3 ((VOS[1:0] bits in PWR_CR register = 0x01), 120 MHz HCLK max frequency	1.08	1.14	1.20	V
		Power Scale 2 ((VOS[1:0] bits in PWR_CR register = 0x10), 144 MHz HCLK max frequency with over-drive OFF or 168 MHz with over-drive ON	1.20	1.26	1.32	
		Power Scale 1 ((VOS[1:0] bits in PWR_CR register = 0x11), 168 MHz HCLK max frequency with over-drive OFF or 180 MHz with over-drive ON	1.26	1.32	1.40	
	Regulator OFF: 1.2 V external voltage must be supplied from external regulator on V_{CAP_1}/V_{CAP_2} pins ⁽⁶⁾	Max frequency 120 MHz	1.10	1.14	1.20	
		Max frequency 144 MHz	1.20	1.26	1.32	
		Max frequency 168 MHz	1.26	1.32	1.38	
V_{IN}	Input voltage on RST and FT pins ⁽⁷⁾	$2 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$	-0.3	-	5.5	V
		$V_{DD} \leq 2 \text{ V}$	-0.3	-	5.2	
	Input voltage on TTa pins	-	-0.3	-	$V_{DDA} + 0.3$	
	Input voltage on BOOT0 pin	-	0	-	9	
P_D	Power dissipation at $T_A = 85^\circ\text{C}$ for suffix 6 or $T_A = 105^\circ\text{C}$ for suffix 7 ⁽⁸⁾	LQFP100	-	-	465	mW
		LQFP144	-	-	500	
		WLCSP168	-	-	645	
		UFBGA169	-	-	385	
		LQFP176	-	-	526	
		UFBGA176	-	-	513	
		LQFP208	-	-	1053	
		TFBGA216	-	-	690	
T_A	Ambient temperature for 6 suffix version	Maximum power dissipation	-40	-	85	°C
		Low power dissipation ⁽⁹⁾	-40	-	105	
	Ambient temperature for 7 suffix version	Maximum power dissipation	-40	-	105	
		Low power dissipation ⁽⁹⁾	-40	-	125	
T_J	Junction temperature range	6 suffix version	-40	-	105	
		7 suffix version	-40	-	125	

1. The over-drive mode is not supported at the voltage ranges from 1.7 to 2.1 V.
2. V_{DD}/V_{DDA} minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to [Section 2.19.2](#)).
3. When the ADC is used, refer to [Table 76](#).
4. If V_{REF+} pin is present, it must respect the following condition: $V_{DDA} - V_{REF+} < 1.2 \text{ V}$.
5. It is recommended to power V_{DD} and V_{DDA} from the same source. A maximum difference of 300 mV between V_{DD} and V_{DDA} can be tolerated during power-up and power-down operation.
6. The over-drive mode is not supported when the internal regulator is OFF.

Table 33. Peripheral current consumption

Peripheral	I _{DD(Typ)} ⁽¹⁾			Unit	
	Scale 1	Scale 2	Scale 3		
AHB1 (up to 180 MHz)	GPIOA	3.16	3.00	2.58	μA/MHz
	GPIOB	2.67	2.62	2.25	
	GPIOC	2.42	2.31	2.10	
	GPIOD	2.22	2.10	1.79	
	GPIOE	2.60	2.48	2.23	
	GPIOF	2.39	2.27	2.08	
	GPIOG	2.27	2.13	1.98	
	GPIOH	2.34	2.20	2.02	
	GPIOI	2.52	2.37	2.17	
	GPIOJ	2.16	2.03	1.86	
	GPIOK	2.20	2.06	1.89	
	OTG_HS+ULPI	36.49	33.89	29.90	
	CRC	0.62	0.55	0.50	
	BKPSRAM	0.83	0.74	0.63	
	DMA1 ⁽²⁾	3.3 x N + 6.8	3 x N + 6.3	2.7 x N + 5.5	
AHB2 (up to 180 MHz)	DMA2 ⁽²⁾	3.4 x N + 5.7	3.1 x N + 5.3	2.8 x N + 4.6	μA/MHz
	DMA2D	33.33	30.66	26.98	
	ETH_MAC				
	ETH_MAC_TX				
	ETH_MAC_RX				
AHB3 (up to 180 MHz)	ETH_MAC_PTP	22.30	20.69	18.19	μA/MHz
	USB_OTG_FS	34.33	31.96	28.35	
AHB2 (up to 180 MHz)	DVCMI	3.61	3.35	2.98	μA/MHz
	RNG	1.94	1.82	1.61	
	CRYP	2.42	2.24	2.00	
	HASH	4.14	3.80	3.35	
AHB3 (up to 180 MHz)	QUADSPI	16.83	15.57	13.83	μA/MHz
	FMC	17.22	15.92	14.00	
Bus matrix ⁽³⁾		12.17	11.19	9.97	μA/MHz

Table 41. Main PLL characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
t_{LOCK}	PLL lock time	VCO freq = 192 MHz	75	-	200	μs	
		VCO freq = 432 MHz	100	-	300		
Jitter ⁽³⁾	Cycle-to-cycle jitter	System clock 120 MHz	RMS	-	25	-	
			peak to peak	-	± 150	-	
	Period Jitter		RMS	-	15	-	
			peak to peak	-	± 200	-	
	Main clock output (MCO) for RMII Ethernet	Cycle to cycle at 50 MHz on 1000 samples	-	32	-	ps	
	Main clock output (MCO) for MII Ethernet	Cycle to cycle at 25 MHz on 1000 samples	-	40	-		
	Bit Time CAN jitter	Cycle to cycle at 1 MHz on 1000 samples	-	330	-		
$I_{DD(PLL)}^{(4)}$	PLL power consumption on VDD	VCO freq = 192 MHz VCO freq = 432 MHz	0.15 0.45	-	0.40 0.75	mA	
$I_{DDA(PLL)}^{(4)}$	PLL power consumption on VDDA	VCO freq = 192 MHz VCO freq = 432 MHz	0.30 0.55	-	0.40 0.85		

1. Take care of using the appropriate division factor M to obtain the specified PLL input clock values. The M factor is shared between PLL and PLLI2S.
2. Guaranteed by design.
3. The use of 2 PLLs in parallel can degrade the Jitter up to +30%.
4. Based on test during characterization.

Table 42. PLLI2S (audio PLL) characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{PLLI2S_IN}	PLLI2S input clock ⁽¹⁾	-	0.95 ⁽²⁾	1	2.10	MHz
f_{PLLI2S_OUT}	PLLI2S multiplier output clock	-	-	-	216	
f_{VCO_OUT}	PLLI2S VCO output	-	192	-	432	
t_{LOCK}	PLLI2S lock time	VCO freq = 192 MHz	75	-	200	μs
		VCO freq = 432 MHz	100	-	300	
Jitter ⁽³⁾	Master I2S clock jitter	Cycle to cycle at 12.288 MHz on 48KHz period, N=432, R=5	RMS	-	90	-
		peak to peak	-	± 280	-	ps
		Average frequency of 12.288 MHz, N=432, R=5 on 1000 samples	-	90	-	ps
	WS I2S clock jitter	Cycle to cycle at 48 KHz on 1000 samples	-	400	-	ps

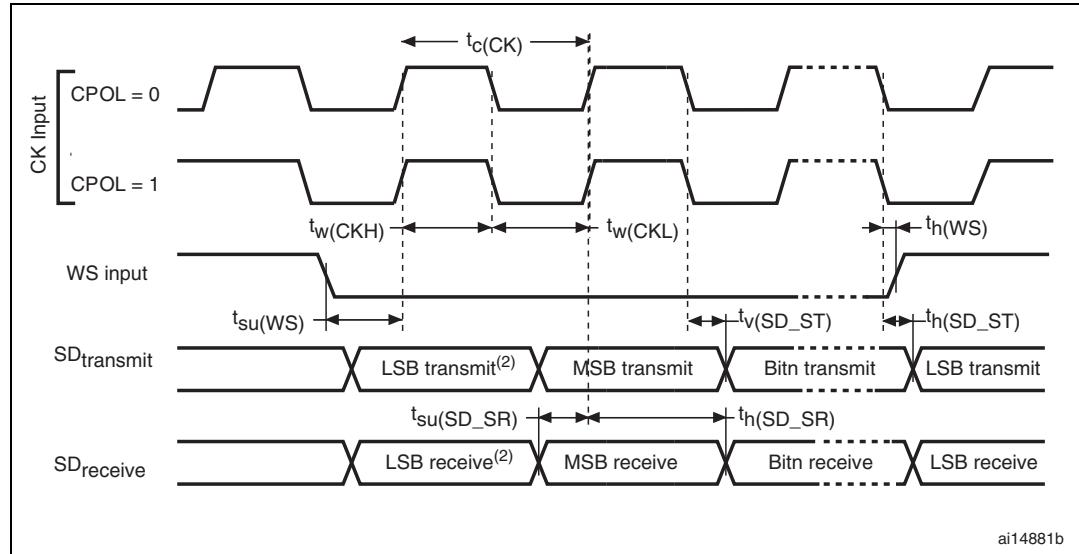
Table 58. I/O static characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
V_{HYS}	FT, TTa and NRST I/O input hysteresis	$1.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$	$10\%V_{DD}^{(3)}$	-	-	V	
	BOOT0 I/O input hysteresis	$1.75 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}, -40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	0.1	-	-		
		$1.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}, 0^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$					
I_{lkg}	I/O input leakage current ⁽⁴⁾	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	± 1	μA	
	I/O FT input leakage current ⁽⁵⁾	$V_{IN} = 5 \text{ V}$	-	-	3		
R_{PU}	Weak pull-up equivalent resistor ⁽⁶⁾	All pins except for PA10/PB12 (OTG_FS_ID, OTG_HS_ID)	$V_{IN} = V_{SS}$	30	40	50	$\text{k}\Omega$
		PA10/PB12 (OTG_FS_ID, OTG_HS_ID)		7	10	14	
R_{PD}	Weak pull-down equivalent resistor ⁽⁷⁾	All pins except for PA10/PB12 (OTG_FS_ID, OTG_HS_ID)	$V_{IN} = V_{DD}$	30	40	50	$\text{k}\Omega$
		PA10/PB12 (OTG_FS_ID, OTG_HS_ID)		7	10	14	
$C_{IO}^{(8)}$	I/O pin capacitance	-	-	5	-	pF	

1. Guaranteed by design.
2. Tested in production.
3. With a minimum of 200 mV.
4. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins. Refer to [Table 57](#)
5. To sustain a voltage higher than $V_{DD} + 0.3 \text{ V}$, the internal pull-up/pull-down resistors must be disabled. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins. Refer to [Table 57](#)
6. Pull-up resistors are designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance is minimum (~10% order).
7. Pull-down resistors are designed with a true resistance in series with a switchable NMOS. This NMOS contribution to the series resistance is minimum (~10% order).
8. Hysteresis voltage between Schmitt trigger switching levels. Based on test during characterization.

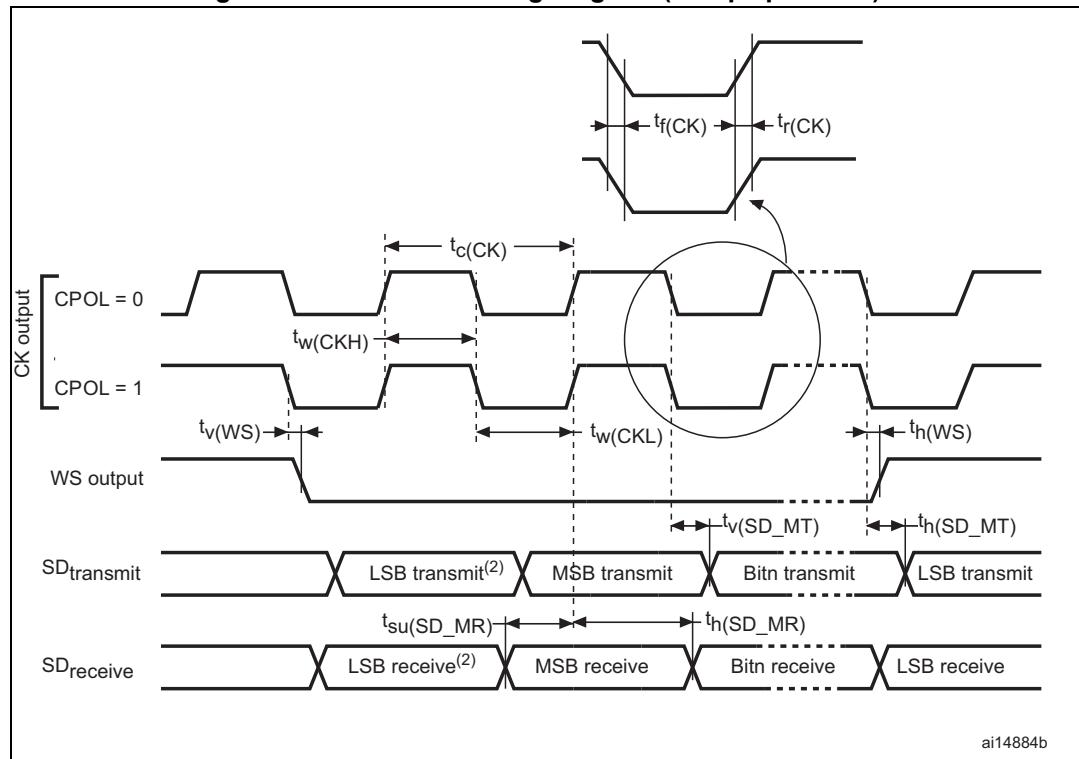
contribution leads to a minimum value of $(I2SDIV/(2*I2SDIV+ODD))$ and a maximum value of $(I2SDIV+ODD)/(2*I2SDIV+ODD)$. F_S maximum value is supported for each mode/condition.

Figure 45. I²S slave timing diagram (Philips protocol)⁽¹⁾



1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

Figure 46. I²S master timing diagram (Philips protocol)⁽¹⁾



1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

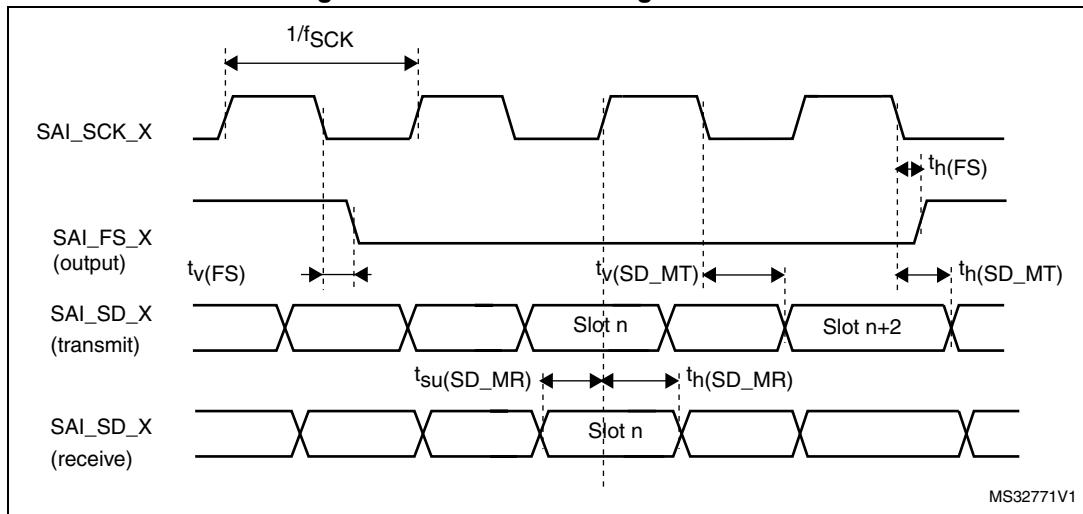
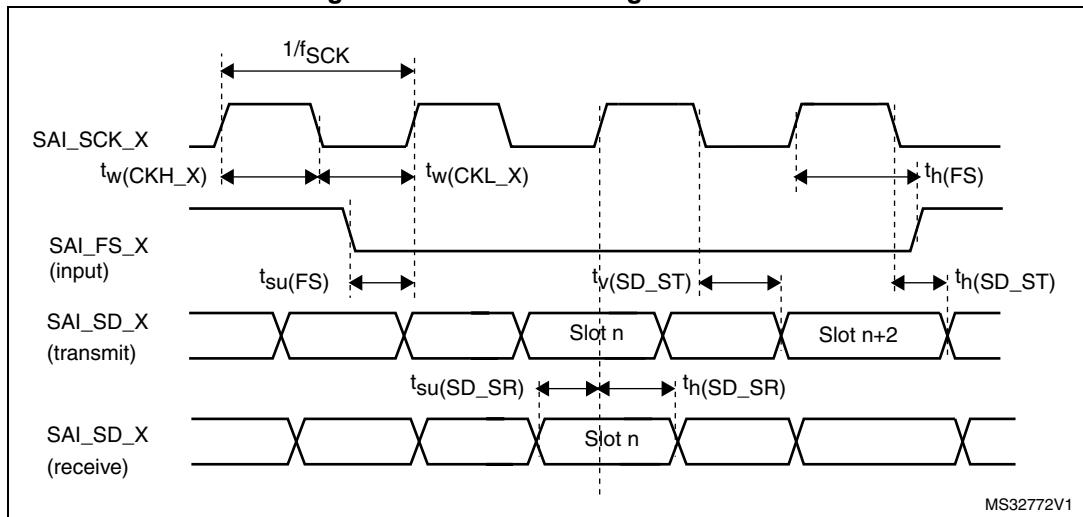
Figure 47. SAI master timing waveforms**Figure 48. SAI slave timing waveforms**

Table 95. Asynchronous multiplexed PSRAM/NOR write-NWAIT timings⁽¹⁾

Symbol	Parameter	Min	Max	Unit
$t_{w(NE)}$	FMC_NE low time	$9T_{HCLK}$	$9T_{HCLK}+0.5$	ns
$t_{w(NWE)}$	FMC_NWE low time	$7T_{HCLK}$	$7T_{HCLK}+2$	
$t_{su(NWAIT_NE)}$	FMC_NWAIT valid before FMC_NEx high	$6T_{HCLK}+1.5$	-	
$t_{h(NE_NWAIT)}$	FMC_NEx hold time after FMC_NWAIT invalid	$4T_{HCLK}-1$	-	

1. Based on test during characterization.

Synchronous waveforms and timings

Figures 63 through 66 represent synchronous waveforms and *Table 96* through *Table 99* provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- BurstAccessMode = FMC_BurstAccessMode_Enable;
- MemoryType = FMC_MemoryType_CRAM;
- WriteBurst = FMC_WriteBurst_Enable;
- CLKDivision = 1;
- DataLatency = 1 for NOR Flash; DataLatency = 0 for PSRAM
- $C_L = 30 \text{ pF}$ on data and address lines. $C_L = 10 \text{ pF}$ on FMC_CLK unless otherwise specified.

In all timing tables, the T_{HCLK} is the HCLK clock period:

- For $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$, maximum FMC_CLK = 90 MHz at $C_L = 30 \text{ pF}$ (on FMC_CLK).
- For $1.71 \text{ V} \leq V_{DD} < 1.9 \text{ V}$, maximum FMC_CLK = 60 MHz at $C_L = 10 \text{ pF}$ (on FMC_CLK).

Table 97. Synchronous multiplexed PSRAM write timings⁽¹⁾

Symbol	Parameter	Min	Max	Unit
$t_w(CLK)$	FMC_CLK period, V_{DD} range= 2.7 to 3.6 V	$2T_{HCLK} - 1$	-	ns
$t_d(CLKL-NExL)$	FMC_CLK low to FMC_NEx low (x=0...2)	-	1.5	
$t_d(CLKH-NExH)$	FMC_CLK high to FMC_NEx high (x= 0...2)	T_{HCLK}	-	
$t_d(CLKL-NADVl)$	FMC_CLK low to FMC_NADV low	-	0	
$t_d(CLKL-NADVh)$	FMC_CLK low to FMC_NADV high	0	-	
$t_d(CLKL-AV)$	FMC_CLK low to FMC_Ax valid (x=16...25)	-	0	
$t_d(CLKH-AIV)$	FMC_CLK high to FMC_Ax invalid (x=16...25)	T_{HCLK}	-	
$t_d(CLKL-NWEL)$	FMC_CLK low to FMC_NWE low	-	0	
$t_d(CLKH-NWEH)$	FMC_CLK high to FMC_NWE high	$T_{HCLK}-0.5$	-	
$t_d(CLKL-ADV)$	FMC_CLK low to FMC_AD[15:0] valid	-	3	
$t_d(CLKL-ADIV)$	FMC_CLK low to FMC_AD[15:0] invalid	0	-	
$t_d(CLKL-DATA)$	FMC_A/D[15:0] valid data after FMC_CLK low	-	3	
$t_d(CLKL-NBLL)$	FMC_CLK low to FMC_NBL low	0	-	
$t_d(CLKH-NBLH)$	FMC_CLK high to FMC_NBL high	$T_{HCLK}-0.5$	-	
$t_{su}(NWAIT-CLKH)$	FMC_NWAIT valid before FMC_CLK high	4	-	
$t_h(CLKH-NWAIT)$	FMC_NWAIT valid after FMC_CLK high	0	-	

1. Based on test during characterization.

Table 111. Dynamic characteristics: SD / MMC characteristics, $V_{DD} = 1.71$ to 1.9 V⁽¹⁾⁽²⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{PP}	Clock frequency in data transfer mode	-	0	-	50	MHz
-	SDIO_CK/fPCLK2 frequency ratio	-	-	-	8/3	-
$t_W(CKL)$	Clock low time	$f_{pp} = 50$ MHz	9.5	10.5	-	ns
$t_W(CKH)$	Clock high time		8.5	9.5	-	
CMD, D inputs (referenced to CK) in eMMC mode						
t_{ISU}	Input setup time HS	$f_{pp} = 50$ MHz	0.5	-	-	ns
t_{IH}	Input hold time HS		3.5	-	-	
CMD, D outputs (referenced to CK) in eMMC mode						
t_{OV}	Output valid time HS	$f_{pp} = 50$ MHz	-	13.5	14.5	ns
t_{OH}	Output hold time HS		13.0	-	-	

1. Guaranteed based on test during characterization.

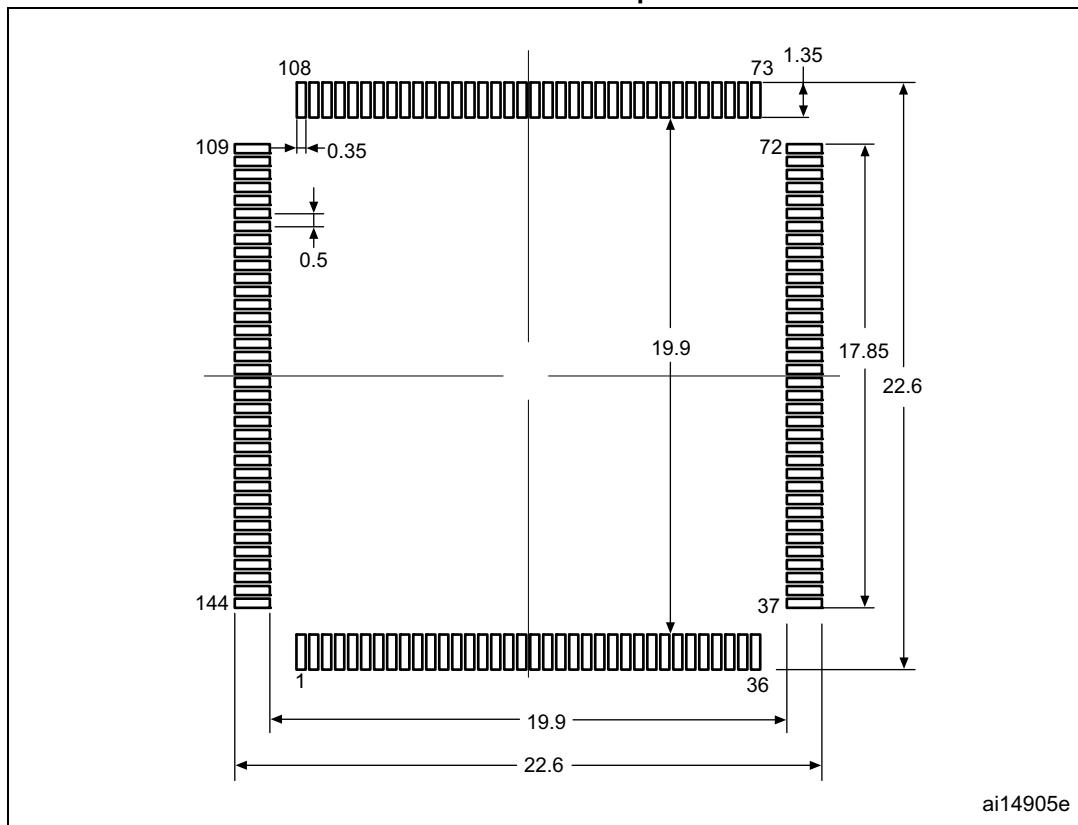
2. $C_{load} = 20$ pF.

5.3.34 RTC characteristics

Table 112. RTC characteristics

Symbol	Parameter	Conditions	Min	Max
-	$f_{PCLK1}/RTCCLK$ frequency ratio	Any read/write operation from/to an RTC register	4	-

Figure 84. LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package recommended footprint

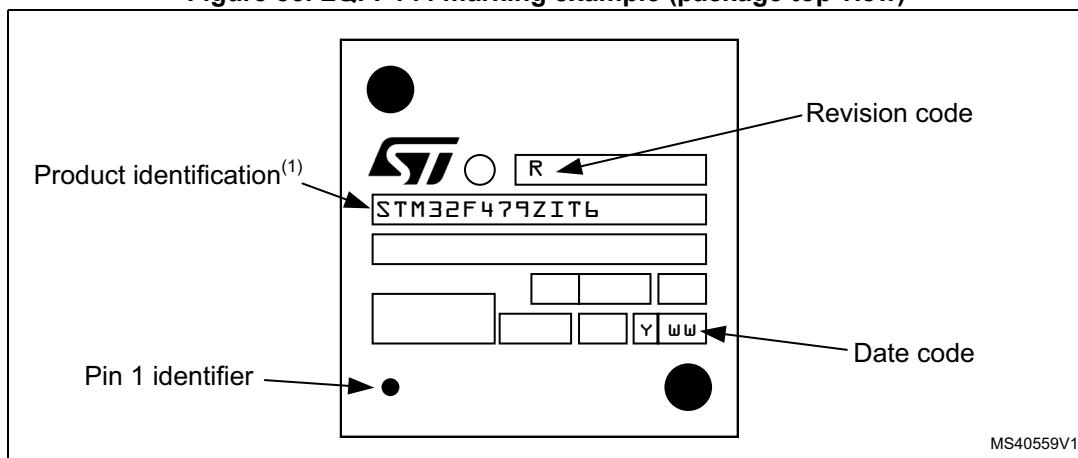


1. Dimensions are expressed in millimeters.

Device Marking for LQFP144

Figure 85 gives an example of topside marking orientation versus pin 1 identifier location. Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

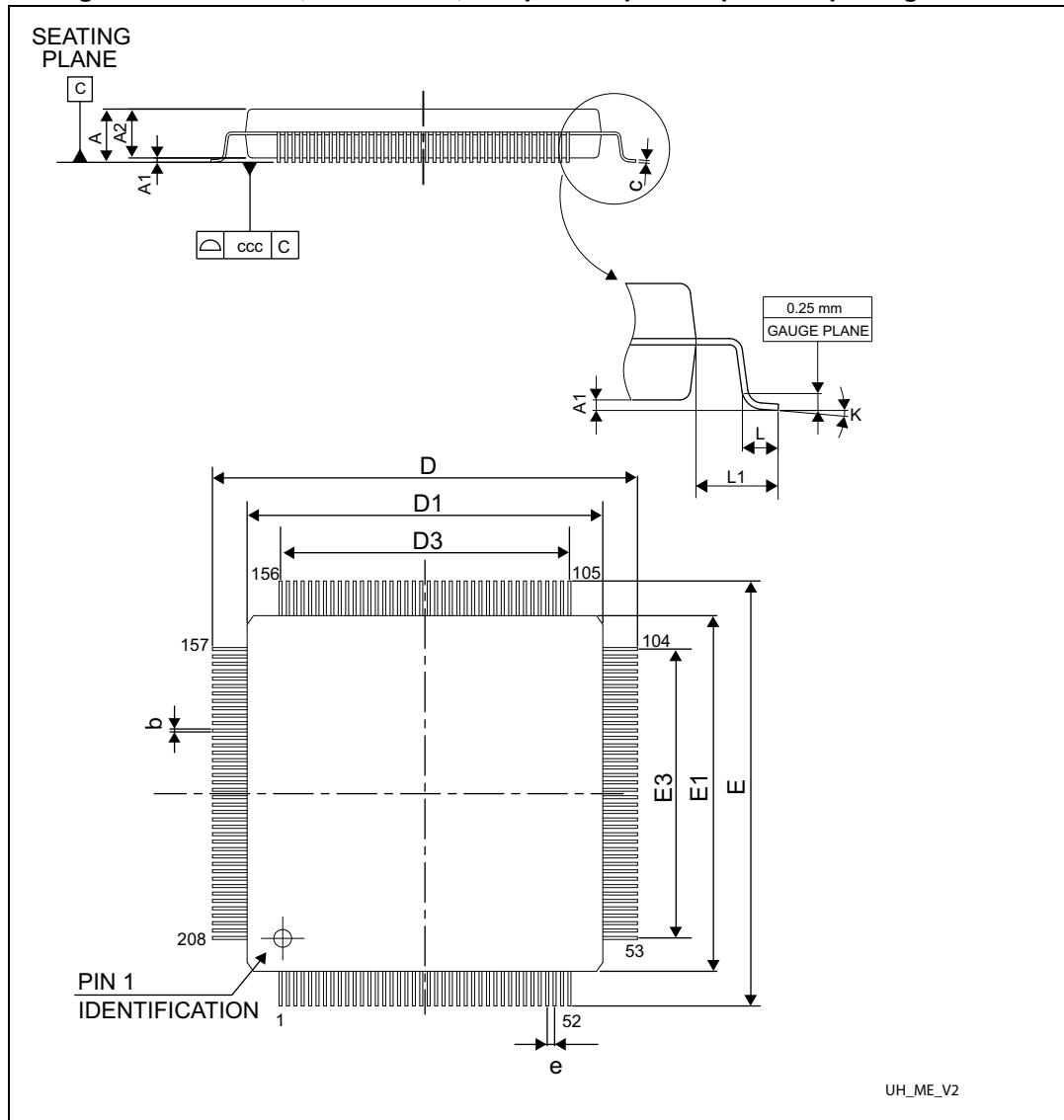
Figure 85. LQFP144 marking example (package top view)



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such

6.7 LQFP208 package information

Figure 94. LQFP208, 28 x 28 mm, 208-pin low-profile quad flat package outline



1. Drawing is not to scale.

Table 120. LQFP208, 28 x 28 mm, 208-pin low-profile quad flat package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	--	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106

6.9 Thermal characteristics

The maximum chip-junction temperature, T_J max, in degrees Celsius, may be calculated using the following equation:

$$T_J \text{ max} = T_A \text{ max} + (P_D \text{ max} \times \Theta_{JA})$$

Where:

- T_A max is the maximum ambient temperature in °C,
- Θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W,
- P_D max is the sum of P_{INT} max and $P_{I/O}$ max (P_D max = P_{INT} max + $P_{I/O}$ max),
- P_{INT} max is the product of I_{DD} and V_{DD} , expressed in Watts. This is the maximum chip internal power.

$P_{I/O}$ max represents the maximum power dissipation on output pins where:

$$P_{I/O} \text{ max} = \sum (V_{OL} \times I_{OL}) + \sum ((V_{DD} - V_{OH}) \times I_{OH}),$$

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 122. Package thermal characteristics

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LQFP100	43	°C/W
	Thermal resistance junction-ambient LQFP144	40	
	Thermal resistance junction-ambient WL CSP168	31	
	Thermal resistance junction-ambient LQFP176 - 24 × 24 mm / 0.5 mm pitch	38	
	Thermal resistance junction-ambient LQFP208 - 28 × 28 mm / 0.5 mm pitch	19	
	Thermal resistance junction-ambient UFBGA169 - 7 × 7mm / 0.5 mm pitch	52	
	Thermal resistance junction-ambient UFBGA176 - 10 × 10 mm / 0.5 mm pitch	39	
	Thermal resistance junction-ambient TFBGA216 - 13 × 13 mm / 0.8 mm pitch	29	

Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org.